MC100LVELT22

3.3V Dual LVTTL/LVCMOS to Differential LVPECL Translator

The MC100LVELT22 is a dual LVTTL/LVCMOS to differential LVPECL translator. Because LVPECL (Low Voltage Positive ECL) levels are used, only +3.3 V and ground are required. The small outline 8-lead package and the low skew, dual gate design of the LVELT22 makes it ideal for applications which require the translation of a clock and a data signal.

- 350 ps Typical Propagation Delay
- <100 ps Output-to-Output Skew
- Flow Through Pinouts
- The 100 Series Contains Temperature Compensation
- LVPECL Operating Range: V_{CC} = 3.0 V to 3.8 V with GND = 0 V
- When Unused TTL Input is left Open, Q Output will Default High

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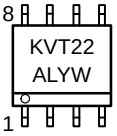
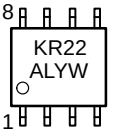
MARKING DIAGRAMS*

SO-8
D SUFFIX
CASE 751



TSSOP-8
DT SUFFIX
CASE 948R



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

*For additional marking information, see Application Note AND8002/D.

ORDERING INFORMATION

Device	Package	Shipping**
MC100LVELT22D	SO-8	98 Units/Rail
MC100LVELT22DR2	SO-8	2500 Units/Reel
MC100LVELT22DT	TSSOP-8	98 Units/Rail
MC100LVELT22DTR2	TSSOP-8	2500 Units/Reel

**For additional tape and reel information, see Brochure BRD8011/D.

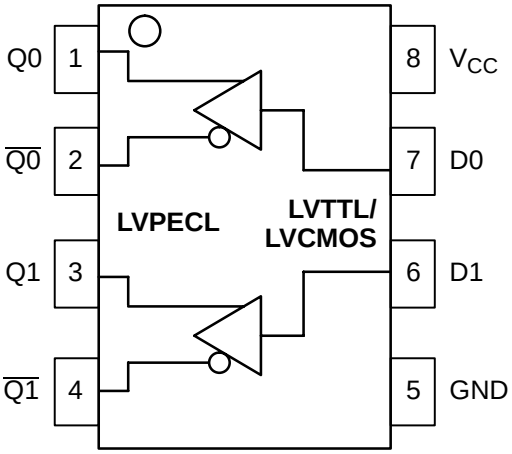


Figure 1. 8-Lead Pinout (Top View)
and Logic Diagram

PIN DESCRIPTION

PIN	FUNCTION
Qn, $\overline{Qn}$	LVPECL Differential Outputs
D0, D1	LVTTL/LVCMOS Inputs
V_{CC}	Positive Supply
GND	Ground

ATTRIBUTES

Characteristics		Value
Internal Input Pulldown Resistor		N/A
Internal Input Pullup Resistor		N/A
ESD Protection	Human Body Model Machine Model	> 4 kV > 200 V
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)		Level 1
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count		164
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test		

1. For additional information, see Application Note AND8003/D.

MAXIMUM RATINGS (Note 2)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V_{CC}	Positive Power Supply	GND = 0 V		7	V
V_I	Input Voltage	GND = 0 V	$V_I \leq V_{CC}$	7	V
I_{out}	Output Current	Continuous Surge		50 100	mA mA
TA	Operating Temperature Range			-40 to +85	°C
T_{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 LFPM 500 LFPM	SO-8 SO-8	190 130	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	std bd	SO-8	41 to 44 ± 5%	°C/W
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 LFPM 500 LFPM	TSSOP-8 TSSOP-8	185 140	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	std bd	TSSOP-8	41 to 44 ± 5%	°C/W
T_{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

2. Maximum Ratings are those values beyond which device damage may occur.

LVPECL DC CHARACTERISTICS V_{CC} = 3.3 V; GND = 0.0 V (Note 3)

		-40 °C			25°C			85°C			
Symbol	Characteristic	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Unit
I_{CC}	Power Supply Current			28			28			29	mA
V_{OH}	Output HIGH Voltage (Note 4)	2275		2420	2275		2420	2275		2420	mV
V_{OL}	Output LOW Voltage (Note 4)	1490		1680	1490		1680	1490		1680	mV

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

3. Output parameters vary 1:1 with V_{CC}. V_{CC} can vary ±0.15 V.
4. Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.

LVTTL/LVCMOS INPUT DC CHARACTERISTICS V_{CC} = 3.3 V; T_A = -40°C to 85°C (Note 5)

Symbol	Characteristic	Min	Typ	Max	Unit	Condition
I_{IH}	Input HIGH Current			20	μA	V_{IN} = 2.7 V
I_{IHH}	Input HIGH Current			100	μA	$V_{IN} = V_{CC}$
I_{IL}	Input LOW Current			-0.2	mA	V_{IN} = 0.5 V
V_{IK}				-1.2	V	I_{IN} = -18 mA
V_{IH}	Input HIGH Voltage	2.0			V	
V_{IL}	Input LOW Voltage			0.8	V	

5. V_{CC} can vary ±0.15 V.

AC CHARACTERISTICS V_{CC} = 3.3 V; GND = 0.0 V (Note 6)

		-40 °C			25°C			85°C			
Symbol	Characteristic	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Unit
f_{max}	Maximum Toggle Frequency					350					MHz
t_{PLH}	Propagation Delay (Note 7)	200	350	600	200	350	600	200	350	600	ps
t_{skew}	Skew Output-to-Output Part-to-Part		30	100 400		30	100 400		30	100 400	ps
tJITTER	Random Clock Jitter (RMS)					1.6					ps
t_r/t_f	Output Rise/Fall Time (20-80%)	200		550	200		500	200		500	ps

6. V_{CC} can vary ±0.15 V.
7. Specifications for standard TTL input signal.

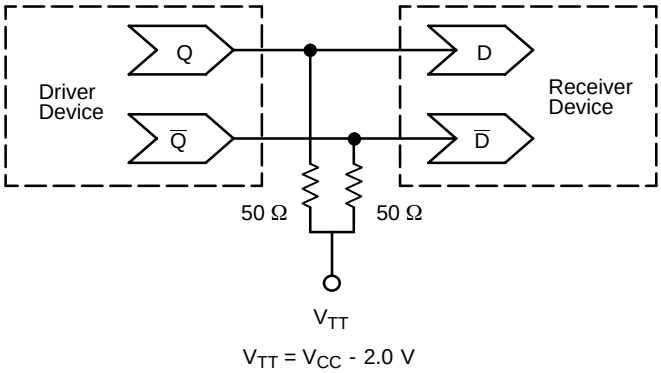


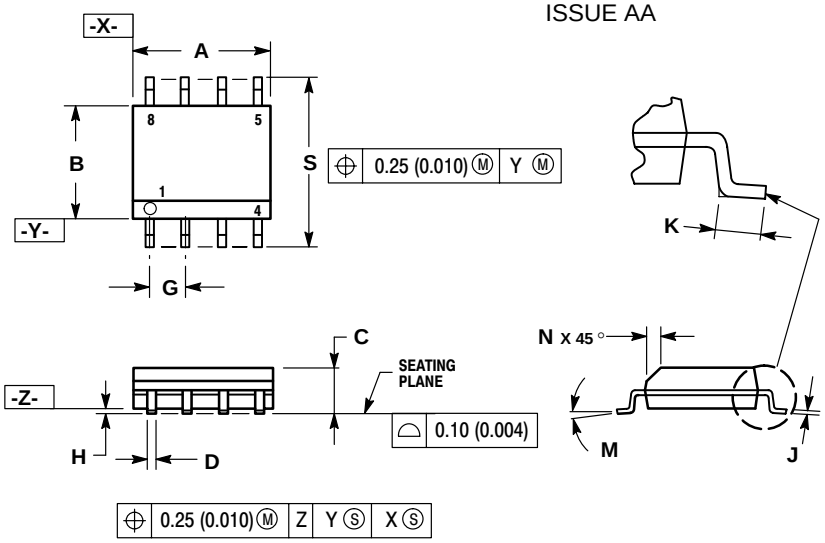
Figure 1. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020 - Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1404	-	ECLinPS Circuit Performance at Non-Standard V_{IH} Levels
AN1405	-	ECL Clock Distribution Techniques
AN1406	-	Designing with PECL (ECL at +5.0 V)
AN1503	-	ECLinPS I/O SPICE Modeling Kit
AN1504	-	Metastability and the ECLinPS Family
AN1560	-	Low Voltage ECLinPS SPICE Modeling Kit
AN1568	-	Interfacing Between LVDS and ECL
AN1596	-	ECLinPS Lite Translator ELT Family SPICE I/O Model Kit
AN1650	-	Using Wire-OR Ties in ECLinPS Designs
AN1672	-	The ECL Translator Guide
AND8001	-	Odd Number Counters Design
AND8002	-	Marking and Date Codes
AND8020	-	Termination of ECL Logic Devices
AND8090	-	AC Characteristics of ECL Devices

PACKAGE DIMENSIONS

SO-8
D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751-07
ISSUE AA

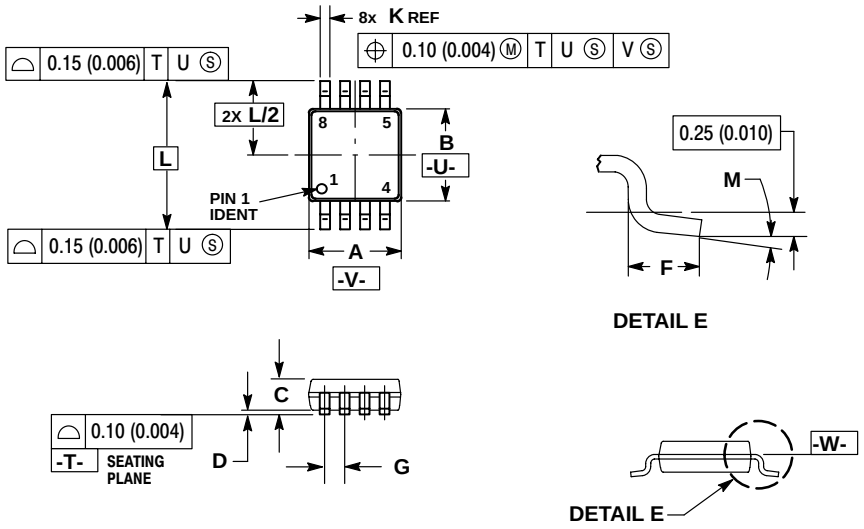


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751−01 THRU 751−06 ARE OBSOLETE. NEW STANDAARD IS 751−07

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

PACKAGE DIMENSIONS

TSSOP-8
DT SUFFIX
PLASTIC TSSOP PACKAGE
CASE 948R-02
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65 BSC		0.026 BSC	
K	0.25	0.40	0.010	0.016
L	4.90 BSC		0.193 BSC	
M	0°	6°	0°	6°

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